Analog Power AM7433P

P-Channel 30-V (D-S) MOSFET

Key Features:

- Low r_{DS(on)} trench technology
- · Low thermal impedance
- · Fast switching speed

Typical Applications:

- · White LED boost converters
- Automotive Systems
- Industrial DC/DC Conversion Circuits

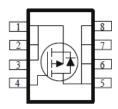
| PRODUCT SUMMARY | | | | |
|---------------------|------------------------------|--------|--|--|
| V _{DS} (V) | $r_{DS(on)}(m\Omega)$ | I□ (A) | | |
| -30 | 9 @ V _{GS} = -10V | -20 | | |
| | 13 @ V _{GS} = -4.5V | -17 | | |



HALOGEN FREE



DFN5X6-8L



| ABSOLUTE MAXIMUM RATINGS (T _A = 25°C UNLESS OTHERWISE NOTED) | | | | | | | |
|---|------------------|--------------------|-----------------|------------|-------|--|--|
| Parameter | | | | Limit | Units | | |
| Drain-Source Voltage | | | | -30 | V | | |
| Gate-Source Voltage | e-Source Voltage | | | | V | | |
| Continuous Drain Comment ^a | | _A =25°C | ı | -20 | | | |
| Continuous Drain Current ^a | Т | _A =70°C | I _D | -16 | Α | | |
| Pulsed Drain Current ^b | | | I _{DM} | -50 | | | |
| Continuous Source Current (Diode Conduction) ^a | I _S | -7.3 | Α | | | | |
| Device Discipation a | | _A =25°C | P _D | 5 | W | | |
| Power Dissipation ^a | Т | _A =70°C | гD | 3.2 | v v | | |
| Operating Junction and Storage Temperature Range | | | | -55 to 150 | °C | | |

| THERMAL RESISTANCE RATINGS | | | | | | | |
|--|--------------|-----------------|-------|------|--|--|--|
| Parameter | Symbol | Maximum | Units | | | | |
| Maximum Junction-to-Ambient ^a | t <= 10 sec | $R_{\theta JA}$ | 25 | °C/W | | | |
| Maximum Junction-to-Ambient | Steady State | IΛθJA | 65 | C/VV | | | |

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Notes

- a. Surface Mounted on 1" x 1" FR4 Board.
- b. Pulse width limited by maximum junction temperature

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Electrical Characteristics

| Parameter | Symbol | Test Conditions | Min | Тур | Max | Unit | |
|---|---------------------|--|-----|-------|-------|-------|--|
| Static | | | | | | | |
| Gate-Source Threshold Voltage | $V_{GS(th)}$ | $V_{DS} = V_{GS}, I_{D} = -250 \text{ uA}$ | -1 | | | V | |
| Gate-Body Leakage | I _{GSS} | $V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$ | | | ±100 | nA | |
| Zara Cata Valta da Duaia Comunant | | $V_{DS} = -24 \text{ V}, V_{GS} = 0 \text{ V}$ | | | -1 uA | | |
| Zero Gate Voltage Drain Current | I _{DSS} | $V_{DS} = -24 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55^{\circ}\text{C}$ | | | -25 | uA | |
| On-State Drain Current ^a | I _{D(on)} | $V_{DS} = -5 \text{ V}, V_{GS} = -10 \text{ V}$ | -30 | | | Α | |
| Dunin Course On Braintana a | r | $V_{GS} = -10 \text{ V}, I_D = -15.3 \text{ A}$ | | | 9 | mΩ | |
| Drain-Source On-Resistance ^a | r _{DS(on)} | $V_{GS} = -4.5 \text{ V}, I_D = -12.3 \text{ A}$ | | | 13 | 11122 | |
| Forward Transconductance a | g _{fs} | $V_{DS} = -15 \text{ V}, I_{D} = -15.3 \text{ A}$ | | 34 | | S | |
| Diode Forward Voltage ^a | V_{SD} | $I_S = -3.7 \text{ A}, V_{GS} = 0 \text{ V}$ | | -0.72 | | V | |
| | | Dynamic ^b | | | | | |
| Total Gate Charge | Q_g | $V_{DS} = -15 \text{ V}, V_{GS} = -4.5 \text{ V},$ | | 140 | | nC | |
| Gate-Source Charge | Q_{gs} | $I_{DS} = -15 \text{ V}, V_{GS} = -4.3 \text{ V},$ $I_{D} = -15.3 \text{ A}$ | | 35 | | | |
| Gate-Drain Charge | Q_{gd} | 1g = 10.0 A | | 62 | | | |
| Turn-On Delay Time | t _{d(on)} | $V_{DS} = -15 \text{ V}, R_{L} = 0.9 \Omega,$ | | 18 | | | |
| Rise Time | t _r | $V_{DS} = -15 \text{ V}, K_L = 0.9 \Omega,$ $I_D = -15.3 \text{ A},$ | | 87 | | ns | |
| Turn-Off Delay Time | t _{d(off)} | $V_{GEN} = -10 \text{ V}, R_{GEN} = 6 \Omega$ | | 345 | | | |
| Fall Time | t _f | VGEN = 10 V, NGEN = 0 12 | | 226 | | | |
| Input Capacitance | C _{iss} | | | 8500 | | | |
| Output Capacitance | C _{oss} | $V_{DS} = -15 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ Mhz}$ | _ | 1291 | | pF | |
| Reverse Transfer Capacitance | C _{rss} | | | 939 | | | |

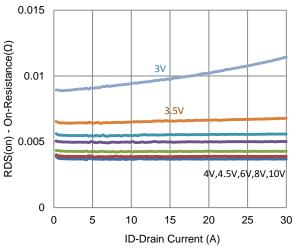
Notes

- Pulse test: PW <= 300us duty cycle <= 2%.
- Guaranteed by design, not subject to production testing. b.

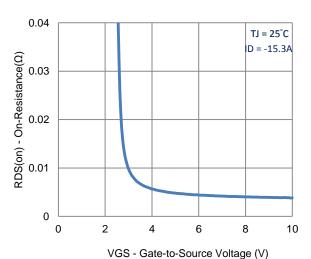
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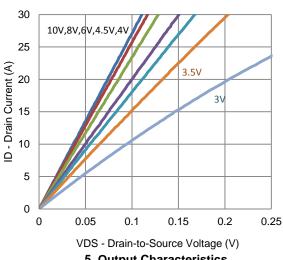
Typical Electrical Characteristics



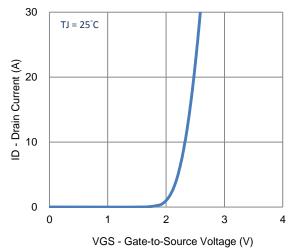
1. On-Resistance vs. Drain Current



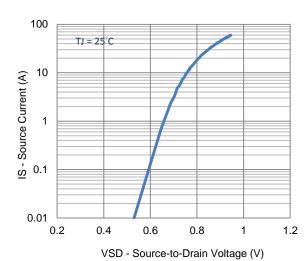
3. On-Resistance vs. Gate-to-Source Voltage



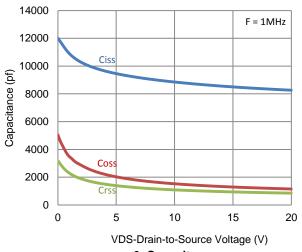
5. Output Characteristics



2. Transfer Characteristics

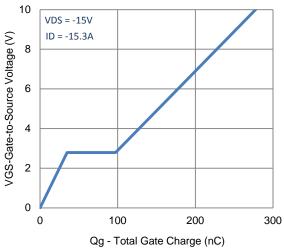


4. Drain-to-Source Forward Voltage

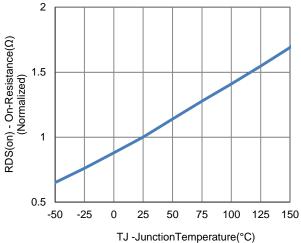


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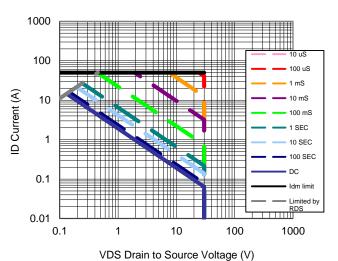
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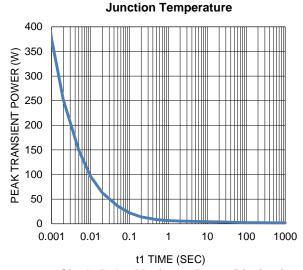




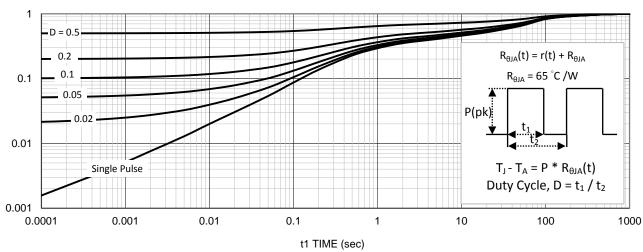
8. Normalized On-Resistance Vs



9. Safe Operating Area



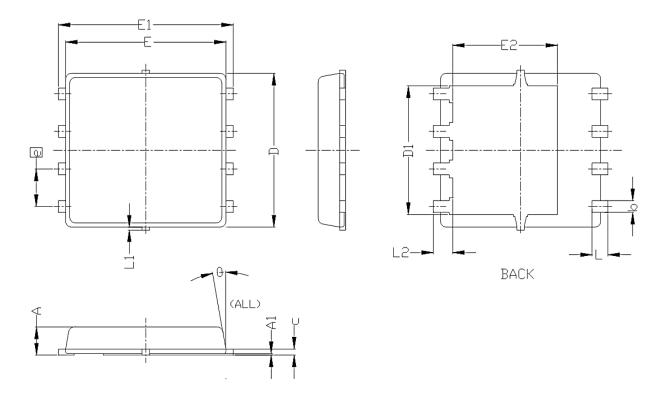
10. Single Pulse Maximum Power Dissipation



11. Normalized Thermal Transient Junction to Ambient

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Package Information



| SYMBOLS | DIMENSIONS IN MILLIMETERS | | | DIMENSIONS IN INCHES | | | |
|---------|---------------------------|-------|-------|----------------------|-------|-------|--|
| STMBOLS | MIN | NOM | MAX | MIN | NOM | MAX | |
| A | 0.85 | 0. 95 | 1.00 | 0.033 | 0.037 | 0.039 | |
| Al | 0.00 | | 0.05 | 0.000 | | 0.002 | |
| b | 0.30 | 0.40 | 0.50 | 0.012 | 0.016 | 0.020 | |
| С | 0.15 | 0. 20 | 0. 25 | 0.006 | 0.008 | 0.010 | |
| D | 5. 20 BSC | | | 0. 205 BSC | | | |
| D1 | 4. 35 BSC | | | 0. 171 BSC | | | |
| | | | | | | | |
| Е | 5, 55 BSC | | | 0. 219 BSC | | | |
| E1 | 6. 05 BSC | | | 0. 238 BSC | | | |
| E2 | 3. 62 BSC | | | 0. 143 BSC | | | |
| e | 1. 27 BSC | | | 0. 050 BSC | | | |
| L | 0.45 | 0.55 | 0.65 | 0.018 | 0.022 | 0.026 | |
| L1 | 0 | | 0.15 | 0 | | 0.006 | |
| L2 | 0.68 REF | | | 0.027 REF | | | |
| θ | 0° | | 10° | 0° | | 10° | |